



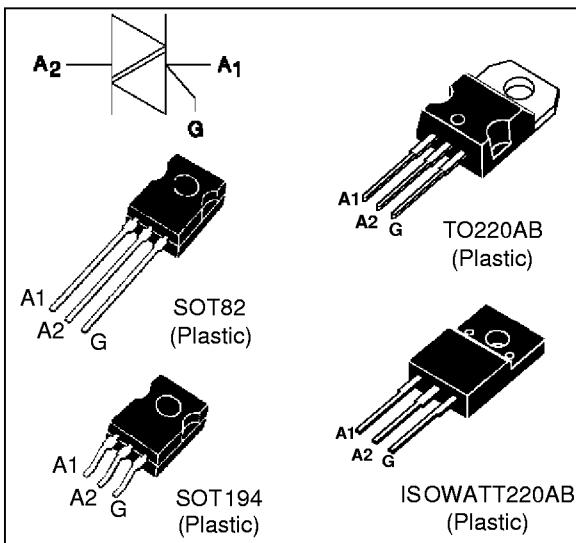
## HIGH PERFORMANCE TRIACS

### FEATURES

- $I_{TRMS} = 4 \text{ A}$
- $V_{DRM} = 400 \text{ V to } 600 \text{ V}$
- SENSITIVE GATE :  $I_{GT} \leq 5 \text{ mA}$
- LOW  $I_H \leq 10 \text{ mA}$

### DESCRIPTION

The T405 high voltage TRIAC Families are high performance planar diffused PNPN devices glass passivated technology. Packaged either in TO220AB, SOT82, SOT194 and ISOWATT220AB these products are intended for all bidirectional switch applications.



### ABSOLUTE RATINGS (limiting values)

| Symbol             | Parameter  |  |                                   | Value                             | Unit                                 |
|--------------------|--|--|-----------------------------------|-----------------------------------|--------------------------------------|
| $I_T(\text{RMS})$  | RMS on-state current<br>( $360^\circ$ conduction angle)  |  | TO220AB<br>SOT194/SOT82           | $T_c = 95 \text{ }^\circ\text{C}$ | A                                    |
|                    |  |  | ISOWATT220AB                      | $T_c = 85 \text{ }^\circ\text{C}$ |                                      |
| $I_{TSM}$          | Non repetitive surge peak on-state current<br>( $T_j$ initial = $25^\circ\text{C}$ )                             |  | $t_p = 8.3 \text{ ms}$            | 35                                | A                                    |
|                    |  |  | $t_p = 10 \text{ ms}$             | 30                                |                                      |
| $I^2t$             | $I^2t$ value   |  | $t_p = 10 \text{ ms}$             | 4.5                               | $\text{A}^2\text{s}$                 |
| $dl/dt$            | Critical rate of rise of on-state current<br>Gate supply : $I_G = 50\text{mA}$ $dI_G/dt = 1\text{A}/\mu\text{s}$ |  | Repetitive<br>$F = 50 \text{ Hz}$ | 10                                | $\text{A}/\mu\text{s}$               |
|                    |  |  | Non<br>Repetitive                 | 50                                |                                      |
| $T_{stg}$<br>$T_j$ | Storage and operating junction temperature range   |  |                                   | - 40 to + 150<br>- 40 to + 110    | $^\circ\text{C}$<br>$^\circ\text{C}$ |
|                    |  |  |                                   | 260                               | $^\circ\text{C}$                     |

| Symbol                 | Parameter   | T405 |      | Unit |
|------------------------|---|------|------|------|
|                        |   | -400 | -600 |      |
| $V_{DRM}$<br>$V_{RRM}$ | Repetitive peak off-state voltage<br>$T_j = 110 \text{ }^\circ\text{C}$ | 400  | 600  | V    |

## THERMAL RESISTANCES

| Symbol                   | Parameter   | Value                     | Unit |
|--------------------------|---|---------------------------|------|
| R <sub>th</sub> (j-a)    | Junction to ambient                                       | SOT82 / SOT194            | 100  |
|                          |   | TO220AB                   | 60   |
|                          |   | ISOWATT220AB              | 50   |
| R <sub>th</sub> (j-c) DC | Junction to case for DC                                   | SOT82 / SOT194<br>TO220AB | 3.5  |
|                          |   | ISOWATT220AB              | 5.3  |
| R <sub>th</sub> (j-c) AC | Junction to case for 360° conduction angle<br>( F= 50 Hz) | SOT82 / SOT194<br>TO220AB | 2.6  |
|                          |   | ISOWATT220AB              | 4    |

## GATE CHARACTERISTICS (maximum values)

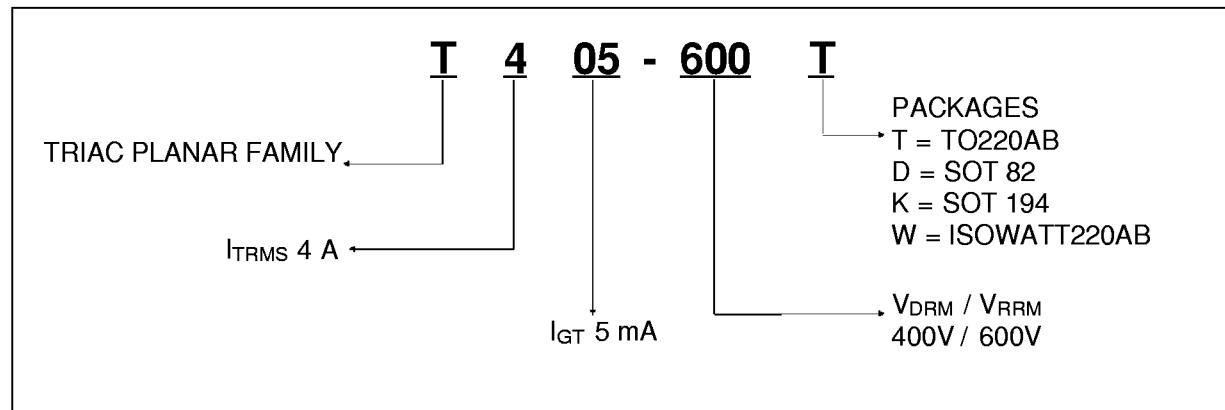
P<sub>G(AV)</sub> = 1 W    P<sub>GM</sub> = 40 W (tp = 20 μs)    I<sub>GM</sub> = 4 A (tp = 20 μs)    V<sub>GM</sub> = 16 V (tp = 20 μs).

## ELECTRICAL CHARACTERISTICS

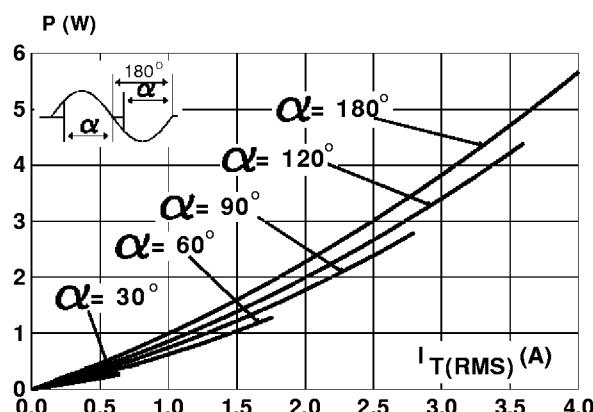
| Symbol                               | Test Conditions   | Quadrant              |          | Value | Unit |
|--------------------------------------|---|-----------------------|----------|-------|------|
| I <sub>GT</sub>                      | V <sub>D</sub> =12V (DC) R <sub>L</sub> =33Ω  | T <sub>j</sub> =25°C  | I-II-III | MAX   | 5    |
| V <sub>GT</sub>                      | V <sub>D</sub> =12V (DC) R <sub>L</sub> =33Ω  | T <sub>j</sub> =25°C  | I-II-III | MAX   | 1.5  |
| V <sub>GD</sub>                      | V <sub>D</sub> =V <sub>DRM</sub> R <sub>L</sub> =3.3kΩ  | T <sub>j</sub> =110°C | I-II-III | MIN   | 0.2  |
| t <sub>gt</sub>                      | V <sub>D</sub> =V <sub>DRM</sub> I <sub>G</sub> = 40mA<br>dI <sub>G</sub> /dt = 0.5A/μs    I <sub>TM</sub> = 5.5A | T <sub>j</sub> =25°C  | I-II-III | TYP   | 2    |
| I <sub>L</sub>                       | I <sub>G</sub> =1.2 I <sub>GT</sub>   |                       | I-III    | MAX   | 10   |
|                                      |   |                       | II       | max   | 15   |
| I <sub>H</sub> *                     | I <sub>T</sub> = 100mA gate open  | T <sub>j</sub> =25°C  |          | MAX   | 10   |
| V <sub>TM</sub> *                    | I <sub>TM</sub> = 5.5A tp= 380μs  | T <sub>j</sub> =25°C  |          | MAX   | 1.75 |
| I <sub>DRM</sub><br>I <sub>RRM</sub> | V <sub>DRM</sub> Rated<br>V <sub>RRM</sub> Rated  | T <sub>j</sub> =25°C  |          | MAX   | 0.01 |
|                                      |   | T <sub>j</sub> =110°C |          | MAX   | 2    |
| dV/dt *                              | Linear slope up to V <sub>D</sub> =67%V <sub>DRM</sub><br>gate open   | T <sub>j</sub> =110°C |          | MIN   | 5    |
|                                      |   |                       |          | TYP   | 20   |
| (dI/dt)c *                           | (dV/dt)c = 0.1V/μs  | T <sub>j</sub> =110°C |          | MIN   | 1.8  |
|                                      |   |                       |          |       | A/ms |

\* For either polarity of electrode A<sub>2</sub> voltage with reference enceenceto electrode A<sub>1</sub>.

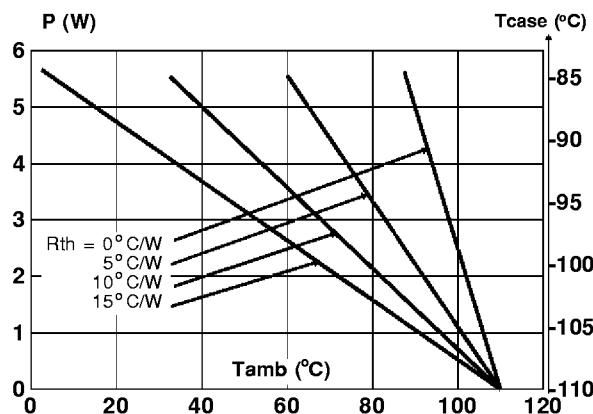
## ORDERING INFORMATION



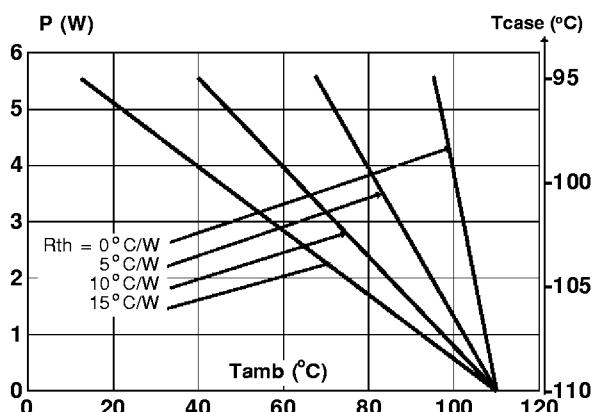
**Fig.1** : Maximum power dissipation versus RMS on-state current ( $F=50\text{Hz}$ ).  
(Curves are cut off by  $(dI/dt)_c$  limitation)



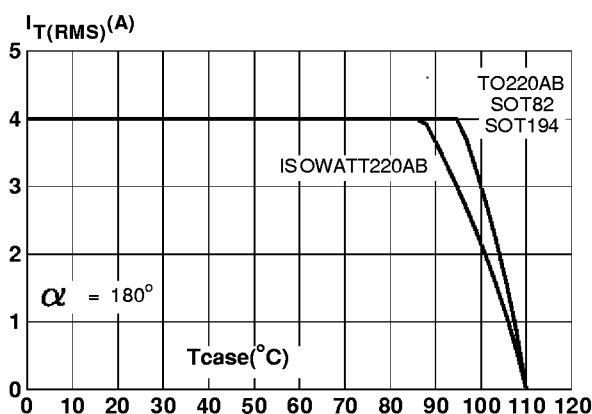
**Fig.3** : Correlation between maximum RMS power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact (ISOWATT220AB).



**Fig.2** : Correlation between maximum power dissipation and maximum allowable temperatures ( $T_{amb}$  and  $T_{case}$ ) for different thermal resistances heatsink + contact (TO220AB / SOT82 / SOT194).

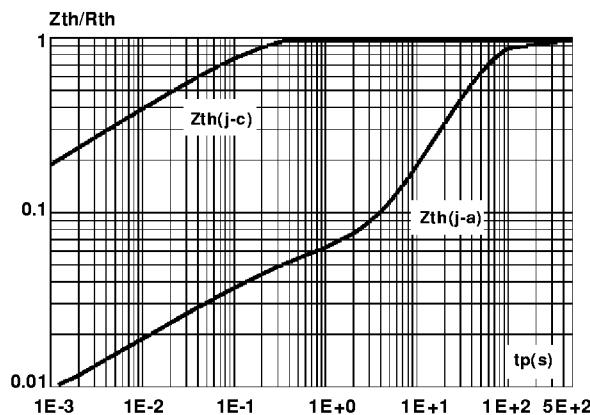


**Fig.4** : RMS on-state current versus case temperature.

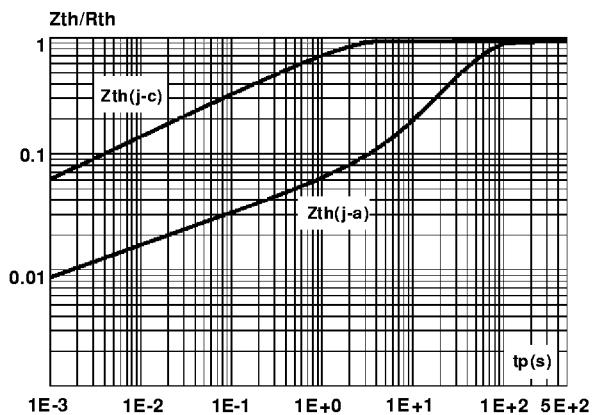


## T405

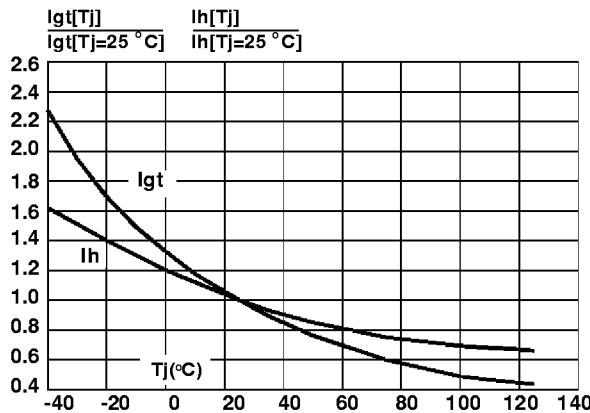
**Fig.5** : Relative variation of thermal impedance versus pulse duration (SOT82 / SOT194 / TO220AB only).



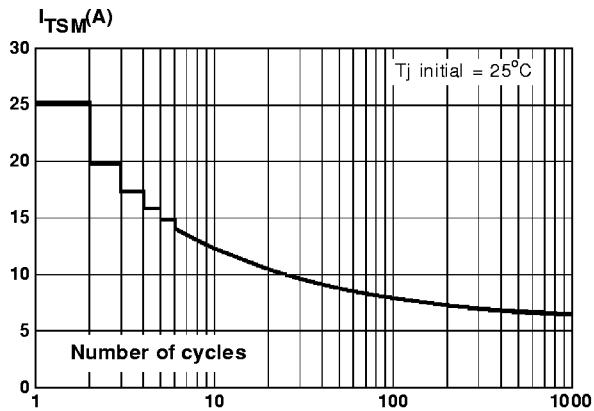
**Fig.6** : Relative variation of thermal impedance versus pulse duration (ISOWATT220AB only).



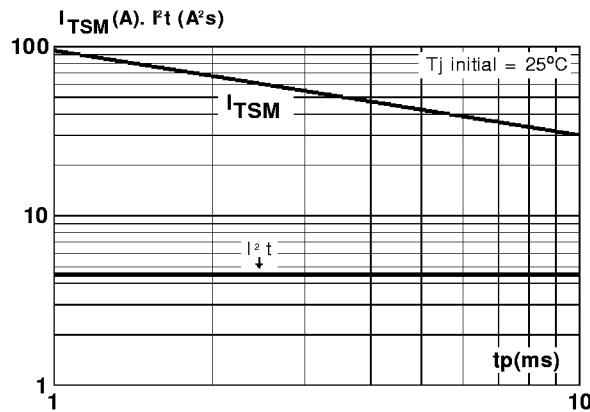
**Fig.7** : Relative variation of gate trigger current and holding current versus junction temperature.



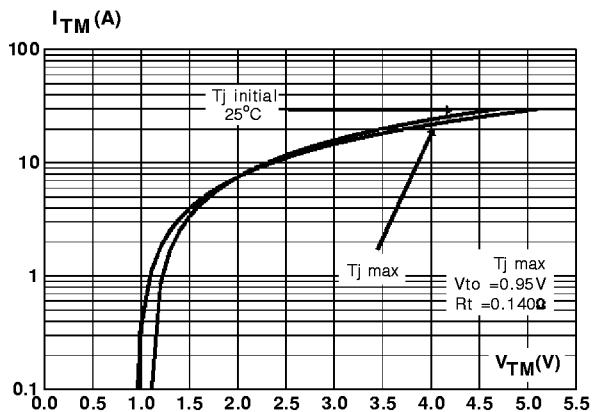
**Fig.8** : Non Repetitive surge peak on-state current versus number of cycles.



**Fig.9** : Non repetitive surge peak on-state current for a sinusoidal pulse with width :  $tp \leq 10\text{ms}$ , and corresponding value of  $I^2t$ .

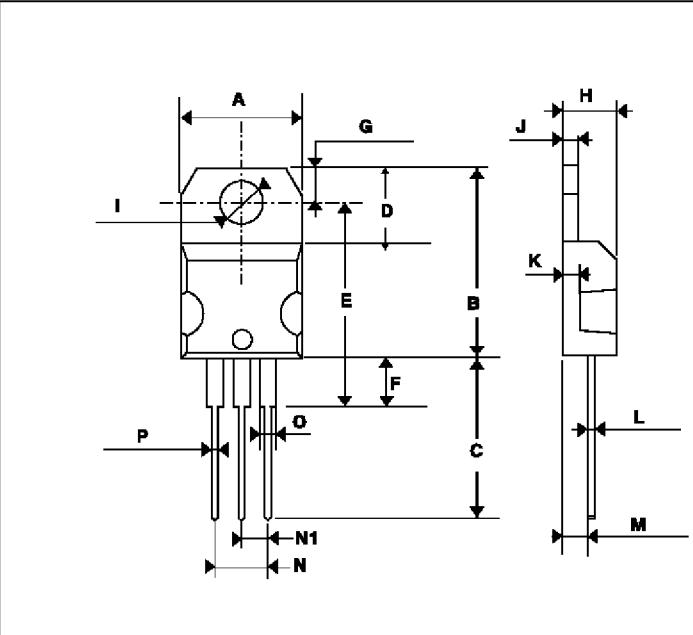


**Fig.10** : On-state characteristics (maximum values).



## PACKAGE MECHANICAL DATA

TO220AB Plastic



| REF. | DIMENSIONS  |      |            |       |
|------|-------------|------|------------|-------|
|      | Millimeters |      | Inches     |       |
|      | Min.        | Max. | Min.       | Max.  |
| A    | 10.0        | 10.4 | 0.393      | 0.409 |
| B    | 15.2        | 15.9 | 0.598      | 0.626 |
| C    | 13          | 14   | 0.511      | 0.551 |
| D    | 6.2         | 6.6  | 0.244      | 0.260 |
| E    | 16.4 typ.   |      | 0.645 typ. |       |
| F    | 3.5         | 4.2  | 0.137      | 0.165 |
| G    | 2.65        | 2.95 | 0.104      | 0.116 |
| H    | 4.4         | 4.6  | 0.173      | 0.181 |
| I    | 3.75        | 3.85 | 0.147      | 0.151 |
| J    | 1.23        | 1.32 | 0.048      | 0.051 |
| K    | 1.27 typ.   |      | 0.050 typ. |       |
| L    | 0.49        | 0.70 | 0.019      | 0.027 |
| M    | 2.4         | 2.72 | 0.094      | 0.107 |
| N    | 4.95        | 5.15 | 0.194      | 0.203 |
| N1   | 2.40        | 2.70 | 0.094      | 0.106 |
| O    | 1.14        | 1.70 | 0.044      | 0.067 |
| P    | 0.61        | 0.88 | 0.024      | 0.034 |

Cooling Method : C

Marking : Type number

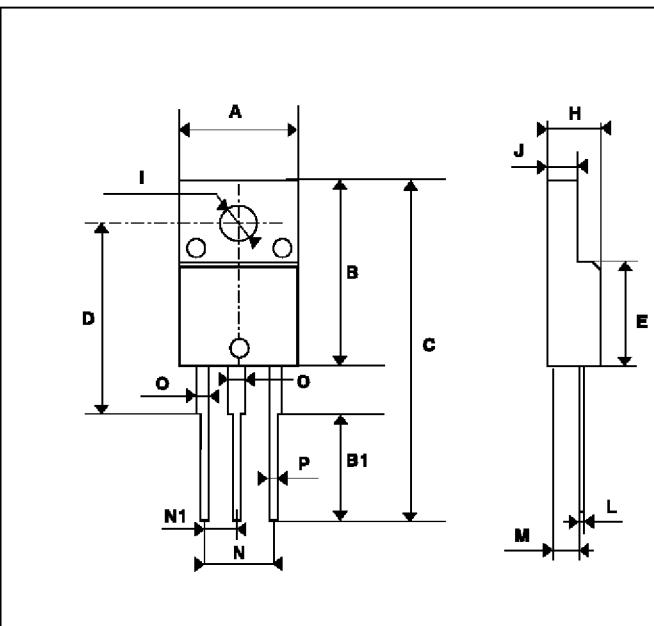
Weight : 2 g

Recommended torque value : 0.55 m.N.

Maximum torque value : 0.70 m.N.

## PACKAGE MECHANICAL DATA

ISOWATT220AB Plastic



| REF. | DIMENSIONS  |      |           |       |
|------|-------------|------|-----------|-------|
|      | Millimeters |      | Inches    |       |
|      | Min.        | Max. | Min.      | Max.  |
| A    | 10          | 10.4 | 0.393     | 0.409 |
| B    | 15.9        | 16.4 | 0.626     | 0.645 |
| B1   | 9.8         | 10.6 | 0.385     | 0.417 |
| C    | 28.6        | 30.6 | 1.126     | 1.204 |
| D    | 16 typ      |      | 0.630 typ |       |
| E    | 9           | 9.3  | 0.354     | 0.366 |
| H    | 4.4         | 4.6  | 0.173     | 0.181 |
| I    | 3           | 3.2  | 0.118     | 0.126 |
| J    | 2.5         | 2.7  | 0.098     | 0.106 |
| L    | 0.4         | 0.7  | 0.015     | 0.027 |
| M    | 2.5         | 2.75 | 0.098     | 0.108 |
| N    | 4.95        | 5.2  | 0.195     | 0.204 |
| N1   | 2.4         | 2.7  | 0.094     | 0.106 |
| O    | 1.15        | 1.7  | 0.045     | 0.067 |
| P    | 0.75        | 1    | 0.030     | 0.039 |

Cooling Method : C

Marking : Type number

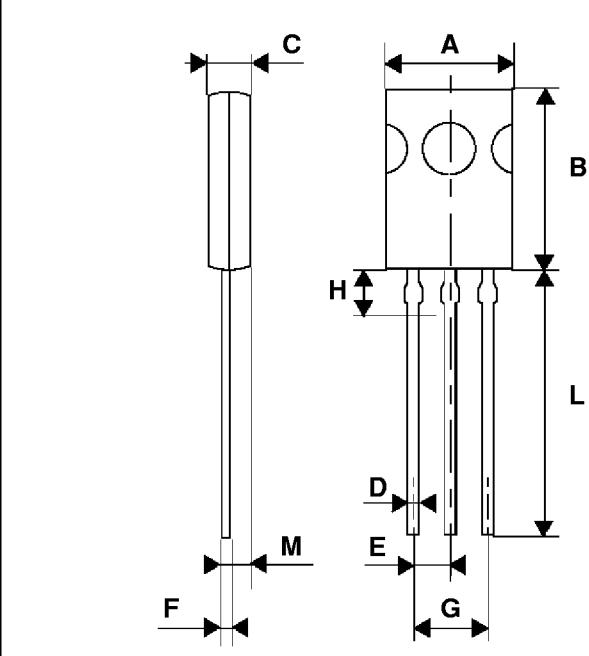
Weight : 2.1g

Recommended torque value : 0.55 m.N.

Maximum torque value : 0.70 m.N.

## PACKAGE MECHANICAL DATA

SOT 82 Plastic



| REF.  | DIMENSIONS  |      |            |       |
|-------|-------------|------|------------|-------|
|       | Millimeters |      | Inches     |       |
|       | Min.        | Max. | Min.       | Max.  |
| A     | 7.4         | 7.8  | 0.291      | 0.307 |
| B     | 10.5        | 10.8 | 0.413      | 0.425 |
| C     | 2.4         | 2.7  | 0.094      | 0.106 |
| D     | 0.7         | 0.9  | 0.027      | 0.035 |
| E     | 2.2 typ.    |      | 0.087 typ. |       |
| F     | 0.49        | 0.75 | 0.019      | 0.029 |
| G     | 4.15        | 4.65 | 0.163      | 0.183 |
| H (1) |             |      | 2.54       |       |
| L     | 15.7 typ.   |      | 0.618 typ. |       |
| M     | 1.0         | 1.3  | 0.039      | 0.051 |

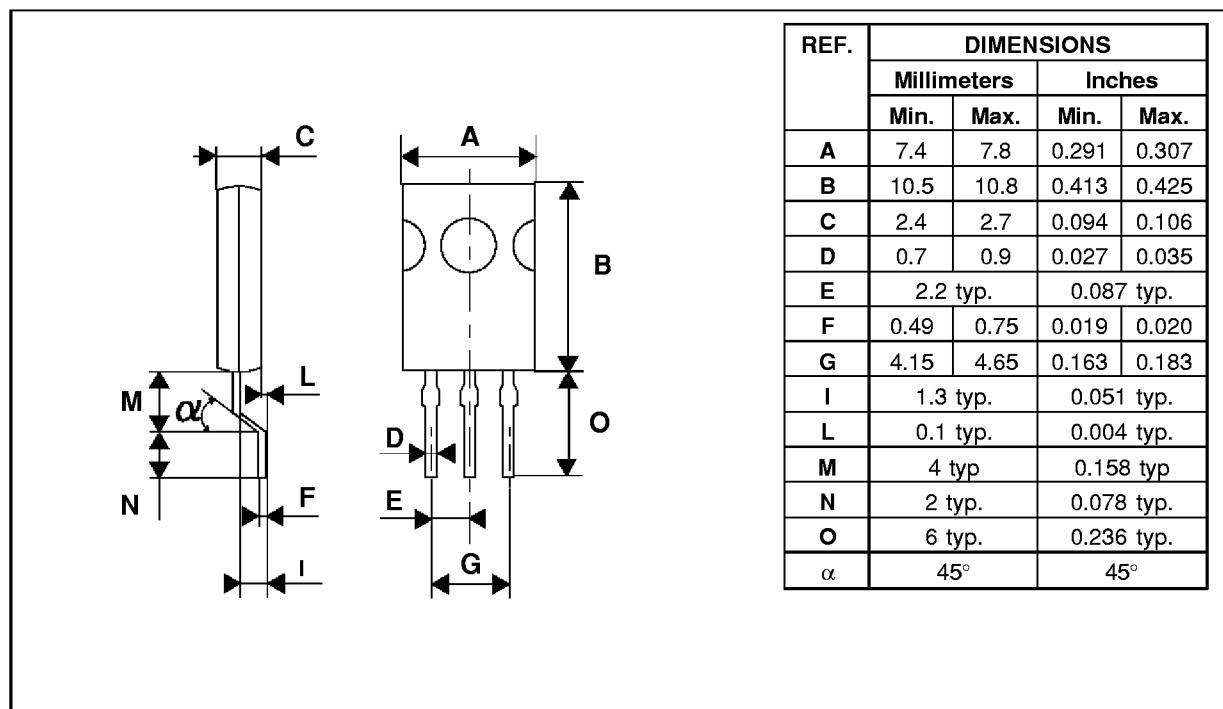
(1) Within this region the cross-section of the leads is uncontrolled

Marking : Type number

Weight : 0.72g

## PACKAGE MECHANICAL DATA

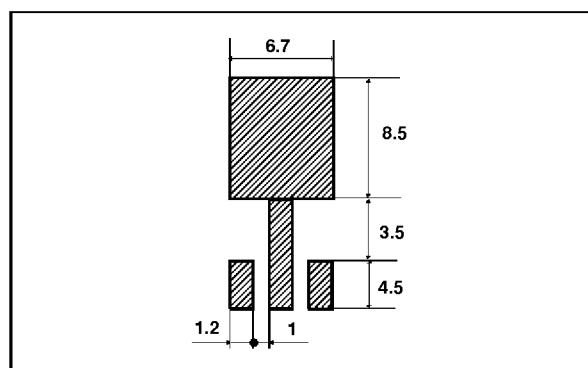
SOT 194 Plastic



Marking : Type number

Weight : 0.68g

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